

BC369



PNP General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.2 A. Sourced from Process 77.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	20	V
V _{CES}	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	1.5	Α
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		BC369	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/∘C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

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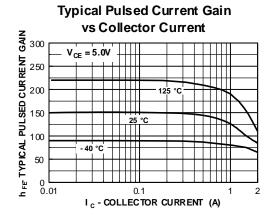
PNP General Purpose Amplifier

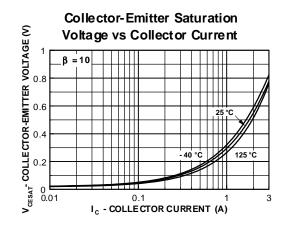
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Electr	Electrical Characteristics TA = 25°C unless otherwise noted					
Symbol	Parameter	Test Conditions	Min	Max	Units	
055.01141	DA OTEDIOTION					
OFF CHAI	RACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	20		V	
$V_{(BR)CES}$	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	25		V	
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V	
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 25 \text{ V}, I_E = 0$ $V_{CB} = 25 \text{ V}, I_E = 0, T_A = 150^{\circ}\text{C}$		10 1.0	μA mA	
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_{C} = 0$		10	μΑ	
ON CHAR	ACTERISTICS DC Current Gain	I_C = 5.0 mA, V_{CE} = 10 V I_C = 0.5 A, V_{CE} = 1.0 V	50 85	375		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 1.0 \text{ A}, V_{CE} = 1.0 \text{ V}$ $I_C = 1.0 \text{ A}, I_B = 100 \text{ mA}$	60	0.5	V	
V _{CE(sat)}	Base-Emitter On Voltage	$I_C = 1.0 \text{ A}, V_{CE} = 1.0 \text{ V}$		1.0	V	
SMALL SI	GNAL CHARACTERISTICS	1 40 mA V 50 V	45	Г	NAL I-	
f _T	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 35 MHz	45		MHz	

NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.

Typical Characteristics

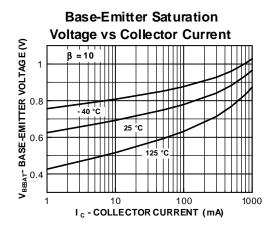


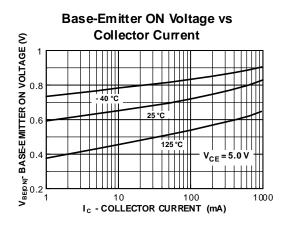


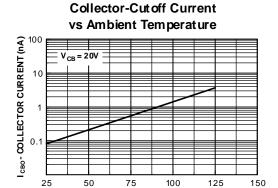
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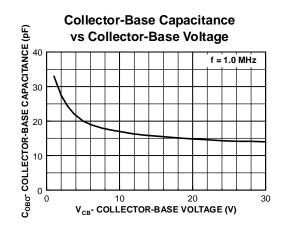
Typical Characteristics (continued)

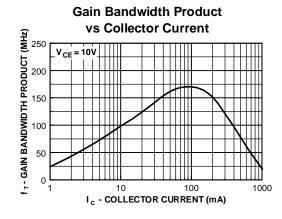


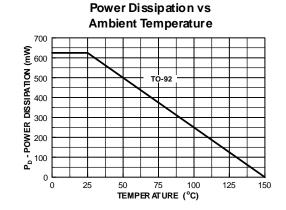




TA-AMBIENT TEMPERATURE (°C)







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